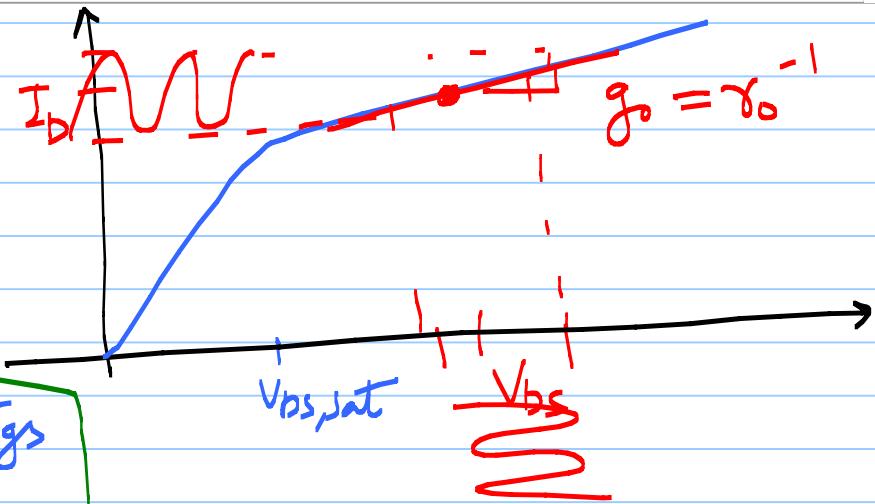
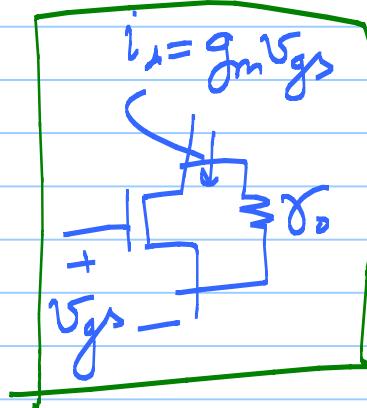
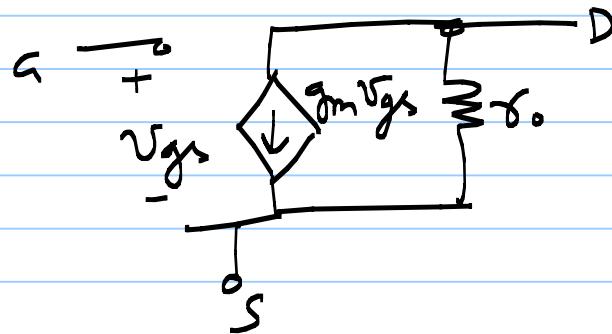


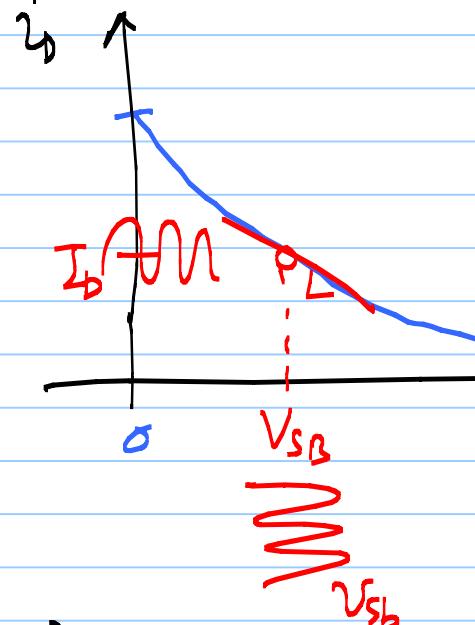
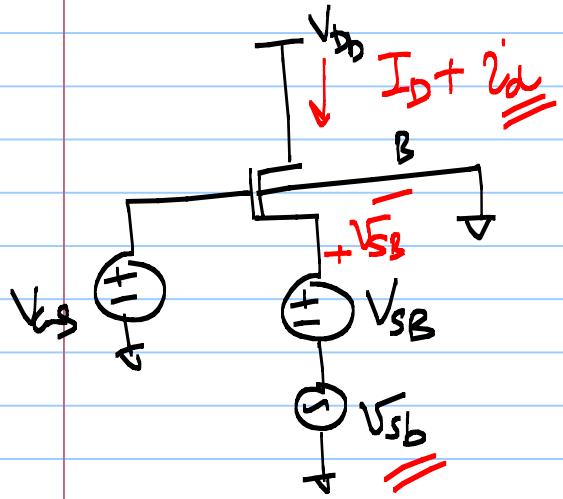
ECE 5411 : Lecture 3.

Note Title

1/26/2011

$$\gamma_0 = \frac{1}{\lambda I_{D,\text{sat}}}$$





incremental
AC
Small - signal

$$V_{SB} = V_{SB} + \Delta V_{SB}$$

$$I_D = f(V_{SB})$$

\downarrow

$$V_{SB} + \Delta V_{SB}$$

\downarrow

$$I_b + \Delta I_b$$

\downarrow

$$\frac{V_{AS}}{V_{DS}}]_{\text{const}}$$

$$i_d = g_{mb} v_{sb}$$

small-signal parameter
(g_{mb})

$$g_m = \left. \frac{\partial i_d}{\partial v_{sb}} \right|_{v_{sb} = V_{SB}}$$

$$= \left. \frac{\partial}{\partial v_{sb}} \left[\frac{K_m}{2} \cdot \frac{1}{L} \cdot (v_{as} - v_{THN})^2 \right] \right|_{v_{sb} = V_{SB}}$$

$$= \left. \frac{K_m}{2} \cdot \frac{1}{L} \cdot 2(v_{as} - v_{THN}) \cdot \left(-\frac{\partial v_{THN}}{\partial v_{sb}} \right) \right|_{v_{sb} = V_{SB}}$$

$$= g_m \cdot \left(-\frac{\partial v_{THN}}{\partial v_{sb}} \right), \quad v_{THN} = f(v_{sb})$$

$$= g_m \cdot \left[-\frac{\gamma}{2} \left(|2V_{sp}| + V_{SB} \right)^{-1/2} \right]$$

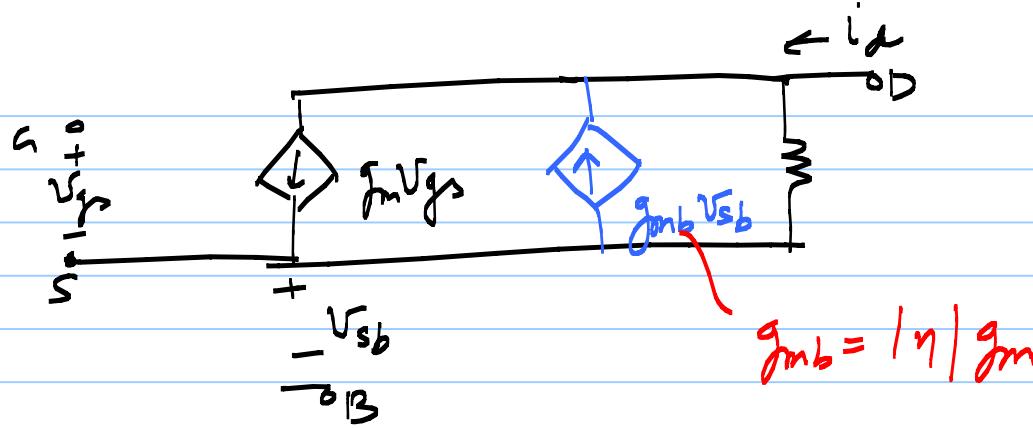
$$\gamma < 0$$

$$|\gamma| < 1$$

$$\boxed{g_{mb} = |\gamma| g_m}$$

$$\gamma = -\frac{\gamma}{2} \frac{1}{\sqrt{|2V_{sp}| + V_{SB}}}$$

* -ve sign in $\gamma \Rightarrow$ indicates that g_{mb} is opposing ' g_m '



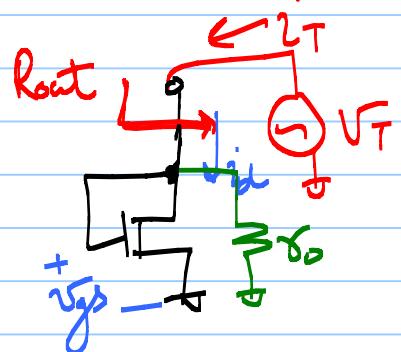
Small signal model
for small frequencies

$$g_{mb} = |\eta| g_m$$

Small - signal parameters

- * g_m
- * γ_0, g_{ds}
- * g_{mb}

Diode connected MOSFET



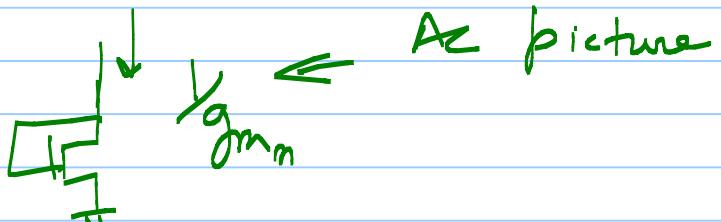
$$\frac{1}{g_m} \parallel r_o = \frac{1}{g_m}$$

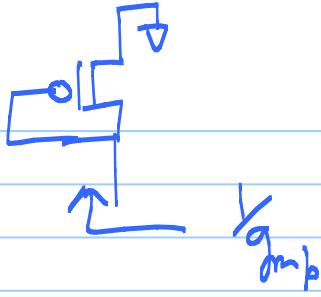
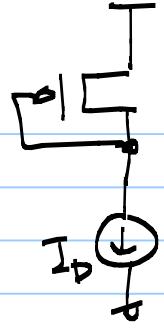
- * Apply a AC test voltage
- * find the AC current

$$\frac{V_T}{i_T} = R_{out}$$

$$R_{out} = \frac{V_T}{i_T} = ?$$

$$= \frac{V_{gs}}{i_D} = \frac{V_{gs}}{g_m V_{gs}} = \frac{1}{g_m}$$





Steps for small-signal analysis

- ① Given a circuit, draw the DC picture
 - ↳ short AC voltage sources
 - ↳ open AC current sources.

Find Bias points for all the devices

- ② Use the DC operating point from ①,
 - ↳ find small-signal parameters
 (g_m, δ_0, \dots)

linearization around the bias point

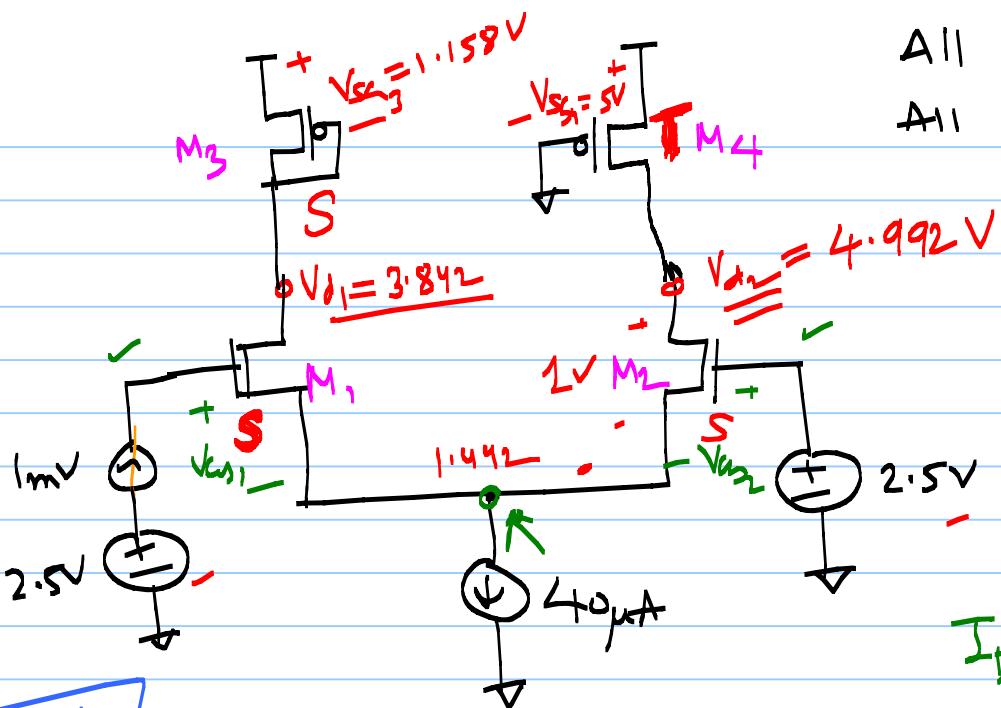
③ Draw the AC picture for the circuit

↳ replace devices by their small-signal models

↳ short DC voltage sources

↳ open DC current sources

Solve for AC values in this circuit.



All NMOS are $10/\mu$
All PMOS are $30/\mu$

1μm process (Table 6.2)

$$V_{DD} = 5V$$

$$V_{THN} = 0.8 \quad V_{THP} = 0.9$$

$$Kp_n = 120 \frac{\mu A}{V^2} \quad Kp_p = 40 \frac{\mu A}{V^2}$$

$$I_{D1} = I_{D2} = 20 \mu A$$

Solve for $V_{GS1} = V_{GS2} = \sqrt{\frac{2I_D \cdot L}{Kp_n W}} + V_{THN}$

$$= \sqrt{\frac{40}{120} \cdot \frac{2}{10}} + 0.8 = 1.058 V$$

$$V_{DS,sat} = V_{GS1} - V_{THN} = 250 \text{ mV}$$

$$V_{S1} = V_{S2} = 2.5 - 1.058 = \boxed{1.442 \text{ V}}$$

M₃

$$V_{SG3} = \sqrt{\frac{2.20}{40} \cdot \frac{2}{30}} + 0.9 = \boxed{1.158 \text{ V}} \Rightarrow \boxed{V_{SD,sat} = 250 \text{ mV}}$$

* M₁ was indeed in Saturation:

M₄ $V_{SG} = 5 \text{ V} \Rightarrow$ most likely M₄ is in Triode

for M₄ to be in Saturation:

$$\Rightarrow V_{SD} \geq V_{SG} - V_{THP}$$

$$V_S - V_D \geq V_S - V_a - V_{THP}$$

$$0 = V_a \geq V_D - V_{THP}$$

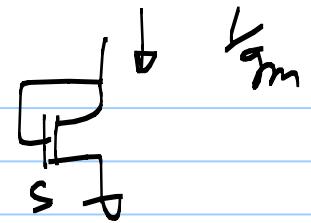
$$\Rightarrow \underline{V_{D_4} \leq 0.9 V}$$

find $V_{D_2} = V_{D_4}$

$$M_4 \Rightarrow 20\mu = 40\mu \cdot \frac{30}{2} \left[(5 - 0.9)V_{SD} - \frac{V_{SD}^2}{2} \right]$$
$$\Rightarrow \boxed{V_{SD_4} = 8.13 mV}$$

$$\Rightarrow V_{D_4} = V_{D_2} = V_{D_3} - V_{SD_4} = \underline{4.992 V}$$

M_2 is in Saturation indeed.

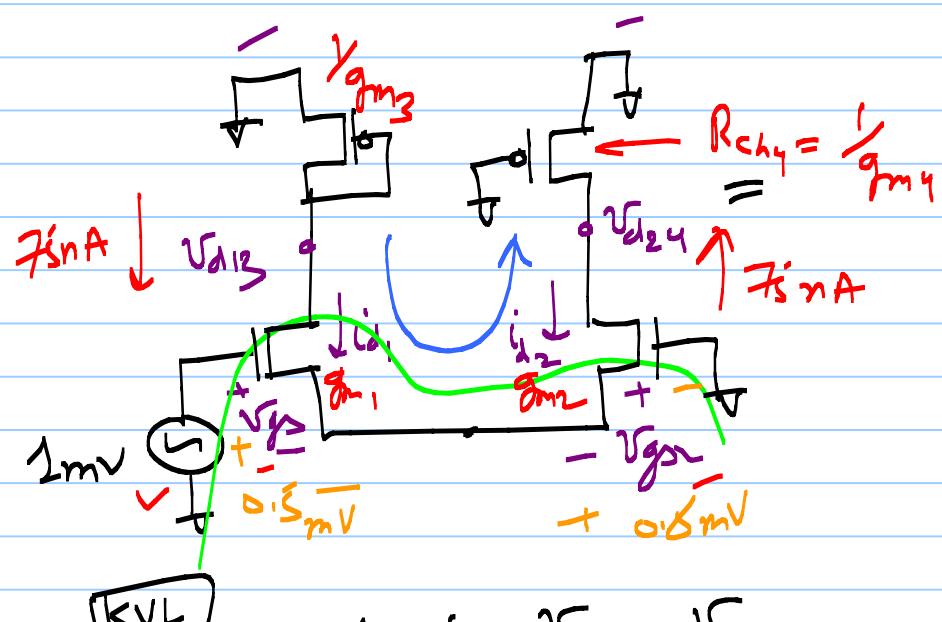


$$R_{ch} = \frac{1}{K P_n W (V_{as} - V_{THN})}$$

\Rightarrow

$$= \frac{1}{g_m}$$

Very
Small



$$M_4 \quad R_{ch4} = 407 \text{ }\Omega$$

M_1, M_2

$$g_m = g_m = \sqrt{2\beta_n I_b} = 150 \frac{\mu A}{V}$$

$$M_3 \quad \frac{1}{g_{m3}} = 6.67 \text{ k}\Omega$$

$$i_{d1} + i_{d2} = 0$$

$$i_{d2} = -i_{d1}$$

$$V_{GS2} = g_m i_{d2} = -g_m i_{d1} = -V_{GS1}$$

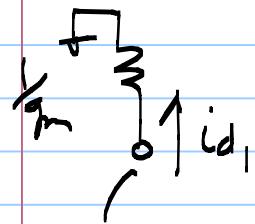
$$\boxed{V_{GS2} = -V_{GS1}} = 0.5mV$$

$$i_{d1} = -i_{d2} = g_m V_{GS1} = \boxed{75 \text{ nA}}$$

$$i_D = I_{D1} + i_{d1} = [20 + 0.075 \cdot \sin(\omega t)] \mu A$$

$$i_{D2} = I_{D2} + i_{d2} = [20 - 0.075 \cdot \sin(\omega t)] \mu A$$

$$i_D + i_{D2} = 40 \mu A$$



$$V_{d_1} = V_{d_3} = -i_d \cdot \frac{1}{g_{m_3}} = -0.5 \text{ mV}$$

(neglected all
vbe's)

$$V_{d_2} = V_{d_4} = -i_{d_4} \cdot R_{ch_4} = 0.03 \text{ mV}$$

$$V_{d_{1,3}} = [3.842 - 0.5 \times 10^3 \sin(\omega t)] \text{ V}$$

$$V_{d_{2,4}} = [4.792 \text{ V} + 0.03 \times 10^3 \sin(\omega t)] \text{ V}$$